APD Semiconductor, Inc.

Super Barrier Rectifier ™

Using state-of-the-art SBR IC process technology,
the following features are made possible in a single device:

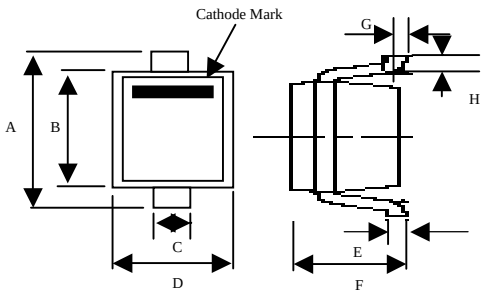
Major ratings and characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular Waveform	1.0 *	A
V_{RRM}	40	V
V_F@1A, T_J=75°C	0.42	V, typ
T_J (operating/storage)	-65 to 125	°C

*Note: Device monuted on a glass epoxy board,
Board size: 50mm x 50m,
Land size: 6mm x 6mm

ELECTRICAL:
* Low Forward Voltage Drop
* Low Reverse Leakage
* Reliable High Temperature Operation
* Super Barrier Design
* Softest, fast switching capability
* 125°C Operating Junction Temperature

MECHANICAL:
* Molded Plastic SOD-323 package



SOD-323		
Di	Min	Max
A	2.30	2.70
B	1.60	1.80
C	0.25	0.40
D	1.15	1.45
E	0.10	0.18
F	0.85	1.05
G	-	0.10
H	0.20	0.40
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics

(at 25°C unless otherwise specified)

	SYMBOL			UNITS
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V_{RM} V_{RWM} V_{RRM}	40		Volts
Average Rectified Forward Current (Rated V_R - 20Khz Square Wave) - 50% duty cycle	I_O (1)	1		Amps
Peak Forward Surge Current - 1/2 60hz	I_{FSM}	18		Amps
Instantaneous Forward Voltage I_F = 0.7A; T_J = 25°C I_F = 1A; T_J = 25°C I_F = 0.7A; T_J = 75°C	V_F	Typ --- 0.44 ---	Max 0.44 --- 0.39	Volts
Maximum Reverse Current at Rated V_{RM} T_J = 25°C T_J = 75°C	I_R (2)	Typ --- ---	Max 0.2 2	mA mA
Operating and Storage Junction Temperature	T_J	-65 to +125		°C

(1) We recommend that the worst case current be no greater than 80% of the maximum rating of I_O

(2) Pulse width < 300 uS, Duty cycle < 2%

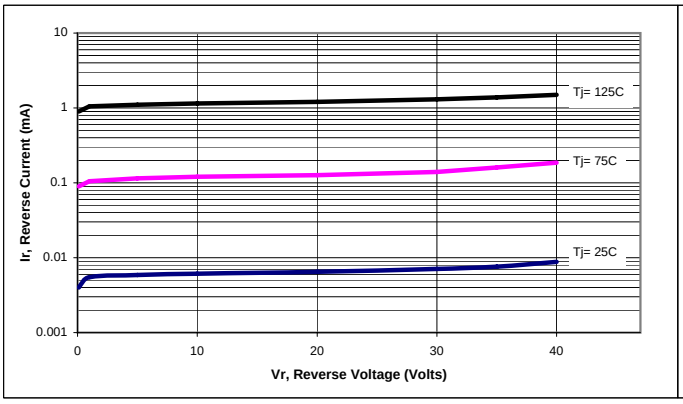


Figure 1: Typical Reverse Current

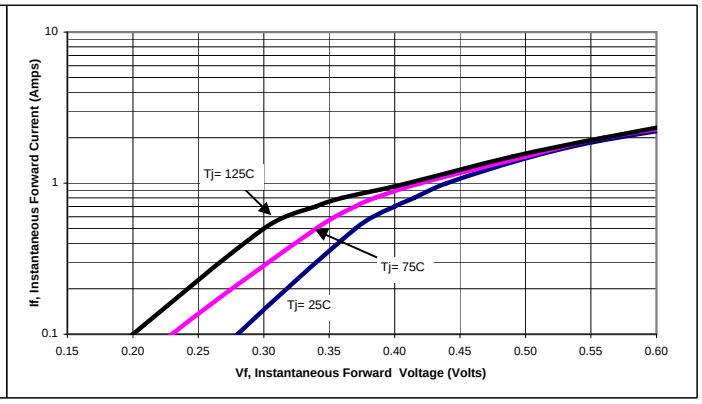


Figure 2: Typical Forward Voltage

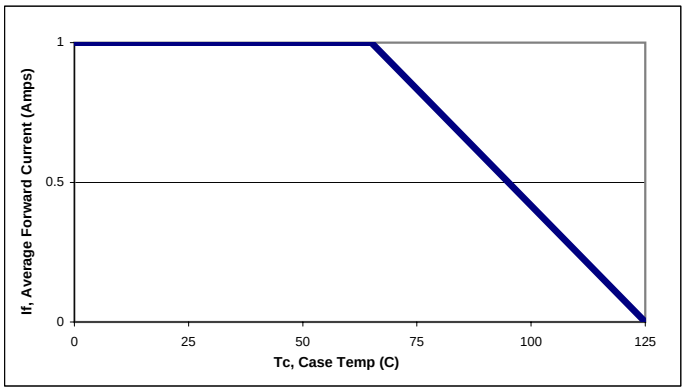
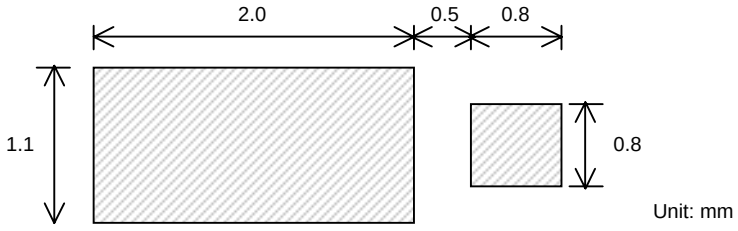


Figure 3: Current Derating, Case*

*Device mounted on a 50mm x 50mm glass epoxy board, 50% duty cycle

STANDARD SOLDERING PAD:



APD Semiconductor, Inc.
1 Lagoon Drive, Suite 410, Redwood City, CA 94065, USA
Ph: 650 508 8896 FAX: 650 508 8865
Homepage: www.apdsemi.com
email: info@apdsemi.com